

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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### **Reflective Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- · High sensitivity
- Wide operating temperature range (- 55°C to +100°C)
- 12.0 in.(305 mm) min. 28 AWG PVC insulated wire leads



#### DESCRIPTION

The HOA1180 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA1180-001, - 002) or photodarlington (HOA1180-003), encased side-by-side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA1180 series employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Wire color code and functions are:

All devices

IRED anode - Red IRED cathode - Black

HOA1180-001

Collector - Brown Emitter - Black

HOA1180-002

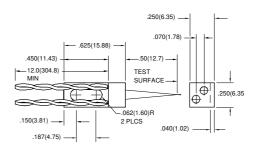
Collector - Orange Emitter - Black

HOA1180-003

Collector - Yellow Emitter - Black

### OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals  $\pm 0.010(0.25)$ 2 plc decimals  $\pm 0.020(0.51)$ 



DIM\_035.ds4

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### **Reflective Sensor**

#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	l₅=20 mA
Reverse Leakage Current	I <sub>R</sub>			10	μΑ	V <sub>R</sub> =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1180-001, -002 HOA1180-003	V <sub>(BR)</sub> ceo	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current HOA1180-001, -002 HOA1180-003	ICEO			100 250	nA	V <sub>CE</sub> =10 V I <sub>F</sub> =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1180-001 HOA1180-002 HOA1180-003	Ic(on)	0.04 0.16 2.0			mA	V <sub>CE</sub> =5 V I <sub>F</sub> =30 mA
Collector-Emitter Saturation Voltage HOA1180-001 HOA1180-002 HOA1180-003	VCE(SAT)			0.4 0.4 1.1	V	I <sub>F</sub> =30 mA <sup>(1)</sup> I <sub>C</sub> =5 μA I <sub>C</sub> =20 μA I <sub>C</sub> =250 μA
Rise And Fall Time HOA1180-001, -002 HOA1180-003	t <sub>r</sub> , t <sub>f</sub>		15 75		μѕ	$V_{CC}$ =5 V, I <sub>C</sub> =1 mA $R_L$ =1000 $\Omega$ $R_L$ =100 $\Omega$

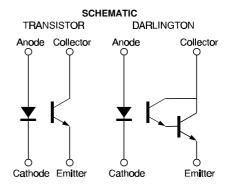
### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -55°C to 100°C Storage Temperature Range -55°C to 125°C Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 75 mW (1) Reverse Voltage 3 V 50 mA Continuous Forward Current **DETECTOR** 

TRANS. **DARLINGTON** 30 V 15 V Collector-Emitter Voltage **Emitter-Collector Voltage** 5 V 5 V 75 mW (1) 75 mW <sup>(1)</sup> Power Dissipation Collector DC Current 30 mA 30 mA

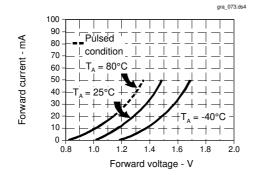


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Notes
1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.50 in.(12.7 mm) from the front surface of the

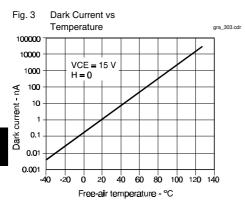
### **Reflective Sensor**

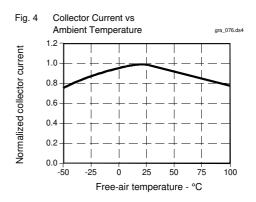
Fig. 1 IRED Forward Bias Characteristics

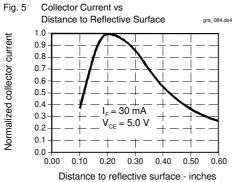


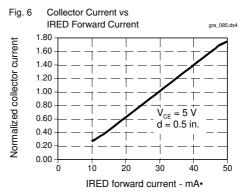
Non-Saturated Switching Time vs Load Resistance gra\_079.ds4 1000 Response time - µs 100 Photodarlington = | | Phototransistor ŦI#I# 10 100 1000 10000

Load resistance - Ohms









All Performance Curves Show Typical Values

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Reflective Sensor

